

**Features**

- Advanced Shield Gate Trench technology
- Super Low Gate Charge
- High-Speed Switching
- 100% EAS Guaranteed
- Green Device Available

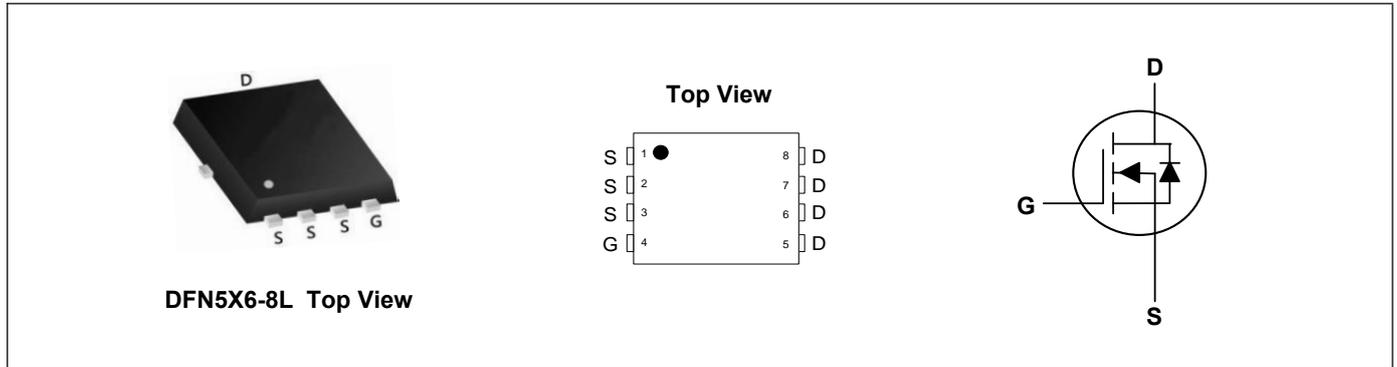
**Applications**

- High Frequency Point-of-Load, Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch

**Product Summary**



|                                  |     |            |
|----------------------------------|-----|------------|
| $V_{DS}$                         | 120 | V          |
| $I_D$                            | 90  | A          |
| $R_{DS(ON)}$ (at $V_{GS}=10V$ )  | 8   | m $\Omega$ |
| $R_{DS(ON)}$ (at $V_{GS}=4.5V$ ) | 10  | m $\Omega$ |



**Absolute Maximum Ratings( $T_C=25^\circ C$ , unless otherwise noted)**

| Parameter                                  | Symbol    | Rating     | Units      |
|--|-----------|------------|------------|
| Drain-Source Voltage                       | $V_{DS}$  | 120        | V          |
| Gate-Source Voltage                        | $V_{GS}$  | $\pm 20$   | V          |
| Continuous Drain Current <sup>1</sup>      | $I_D$     | 90         | A          |
| Continuous Drain Current <sup>1</sup>      | $I_D$     | 57         | A          |
| $T_C=100^\circ C$                          |           |            |            |
| Pulsed Drain Current <sup>2</sup>          | $I_{DM}$  | 360        | A          |
| Single Pulse Avalanche Energy <sup>3</sup> | $E_{AS}$  | 100        | mJ         |
| Total Power Dissipation                    | $P_D$     | 125        | W          |
| Storage Temperature Range                  | $T_{STG}$ | -55 to 150 | $^\circ C$ |
| Operating Junction Temperature Range       | $T_J$     | -55 to 150 | $^\circ C$ |

**Thermal Characteristics**

| Parameter  | Symbol          | Typ | Max | Unit         |
|--|-----------------|-----|-----|--------------|
| Thermal Resistance Junction-Ambient <sup>1</sup> | $R_{\theta JA}$ | --- | 30  | $^\circ C/W$ |
| Thermal Resistance Junction-Case <sup>1</sup>    | $R_{\theta JC}$ | --- | 1   | $^\circ C/W$ |

**Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise noted)**

| Parameter                         | Symbol              | Conditions  | Min | Typ  | Max  | Unit |
|-----------------------------------|---------------------|---|-----|------|------|------|
| Drain-Source Breakdown Voltage    | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =250uA  | 120 | ---  | ---  | V    |
| Static Drain-Source On-Resistance | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =20A   | --- | 6.5  | 8    | mΩ   |
|                                   |                     | V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A  | --- | 8    | 10   | mΩ   |
| Gate Threshold Voltage            | V <sub>GS(th)</sub> | V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =250uA                            | 1.2 | ---  | 2.5  | V    |
| Drain-Source Leakage Current      | I <sub>DSS</sub>    | V <sub>DS</sub> =120V, V <sub>GS</sub> =0V  | --- | ---  | 1    | uA   |
| Gate-Source Leakage Current       | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V  | --- | ---  | ±100 | nA   |
| Gate Resistance                   | R <sub>g</sub>      | V <sub>DS</sub> =0V, V <sub>GS</sub> =0V, f=1MHz                                    | --- | 1.2  | ---  | Ω    |
| Total Gate Charge                 | Q <sub>g</sub>      | V <sub>DD</sub> =60V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A                     | --- | 54   | ---  | nC   |
| Gate-Source Charge                | Q <sub>gs</sub>     |   | --- | 13   | ---  |      |
| Gate-Drain Charge                 | Q <sub>gd</sub>     |   | --- | 7    | ---  |      |
| Turn-On Delay Time                | T <sub>d(on)</sub>  | V <sub>DD</sub> =60V, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω, I <sub>D</sub> =20A | --- | 12   | ---  | ns   |
| Rise Time                         | T <sub>r</sub>      |   | --- | 40   | ---  |      |
| Turn-Off Delay Time               | T <sub>d(off)</sub> |   | --- | 30   | ---  |      |
| Fall Time                         | T <sub>f</sub>      |   | --- | 38   | ---  |      |
| Input Capacitance                 | C <sub>iss</sub>    | V <sub>DS</sub> =60V, V <sub>GS</sub> =0V, f=1MHz                                   | --- | 3900 | ---  | pF   |
| Output Capacitance                | C <sub>oss</sub>    |   | --- | 1360 | ---  |      |
| Reverse Transfer Capacitance      | C <sub>rss</sub>    |   | --- | 20   | ---  |      |

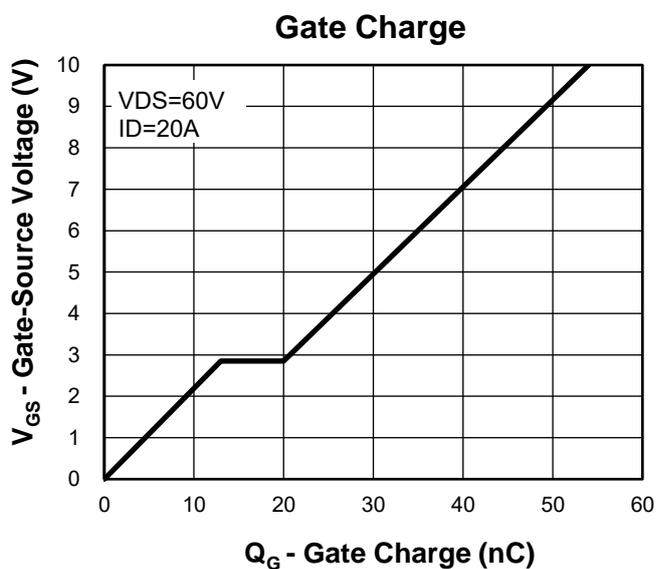
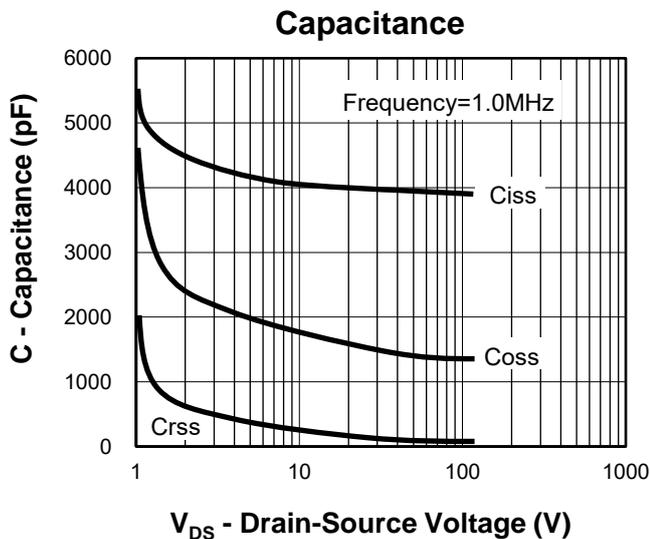
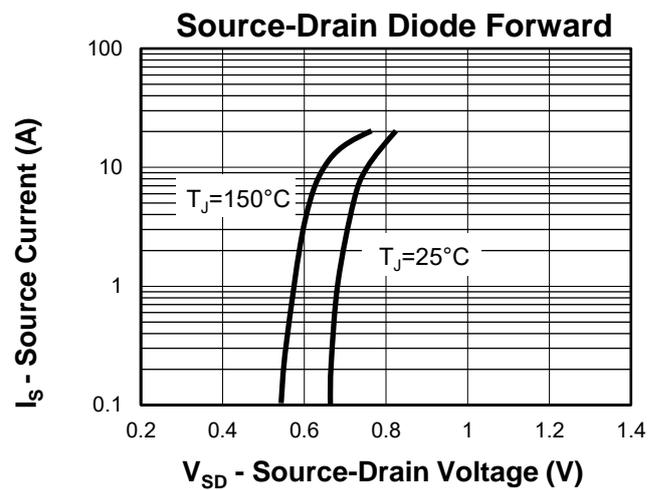
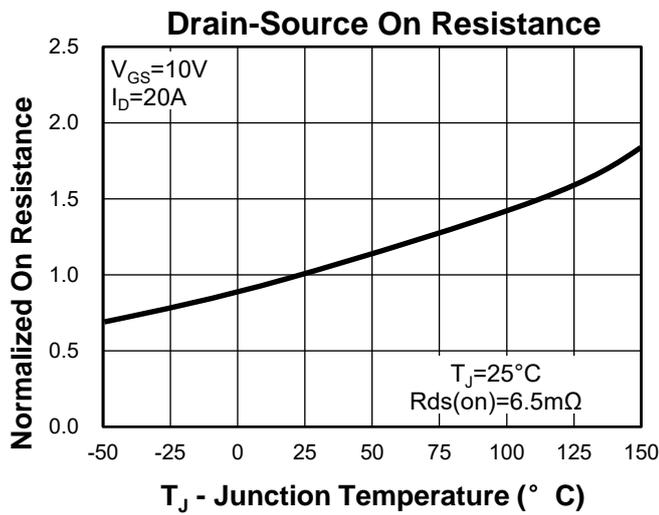
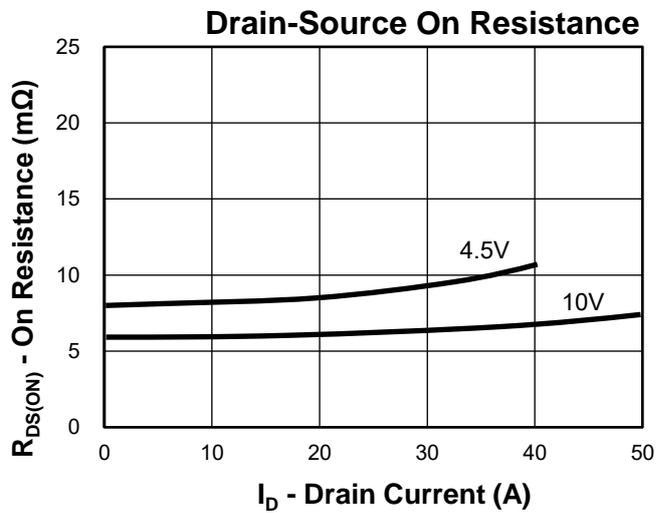
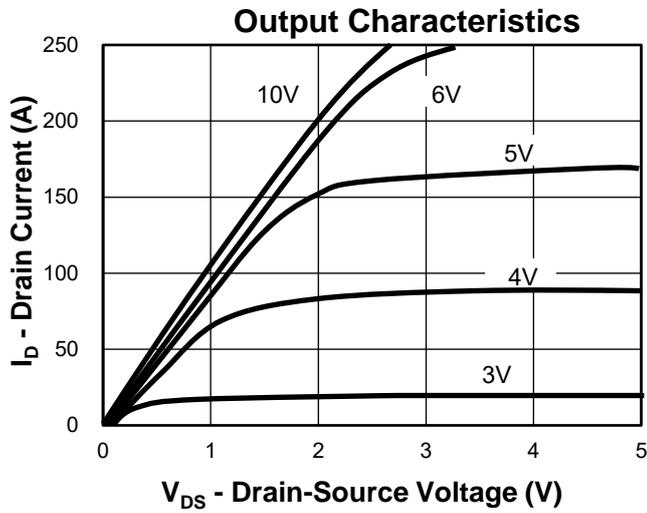
**Drain-Source Diode Characteristics**

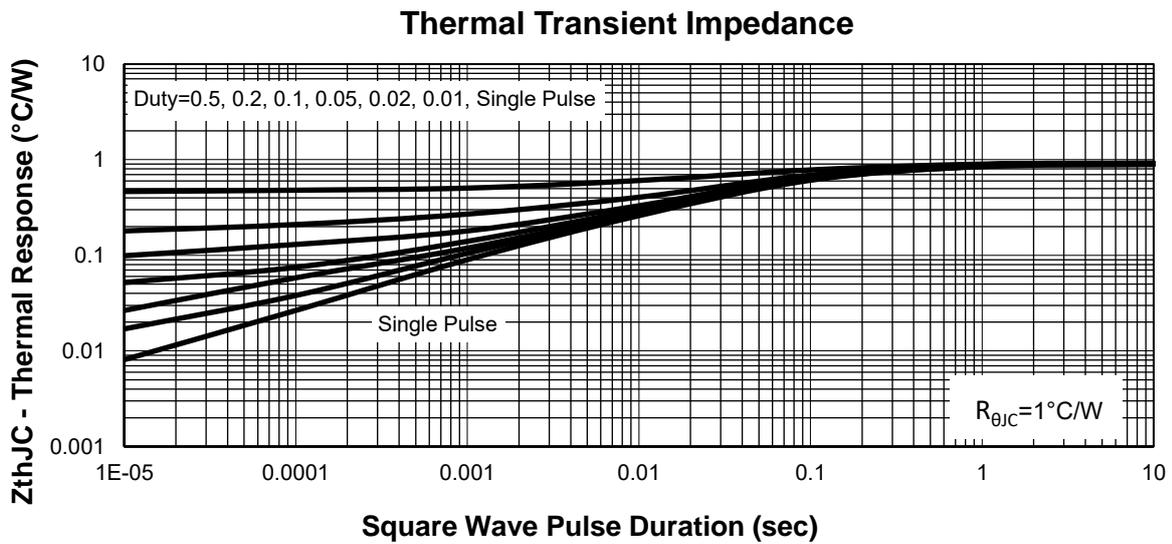
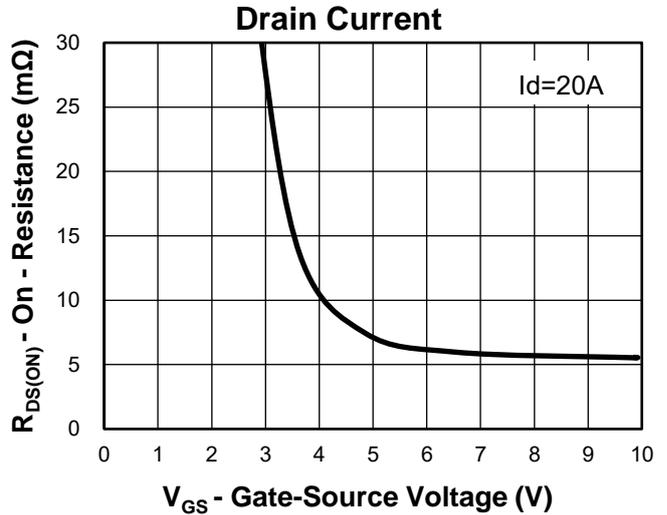
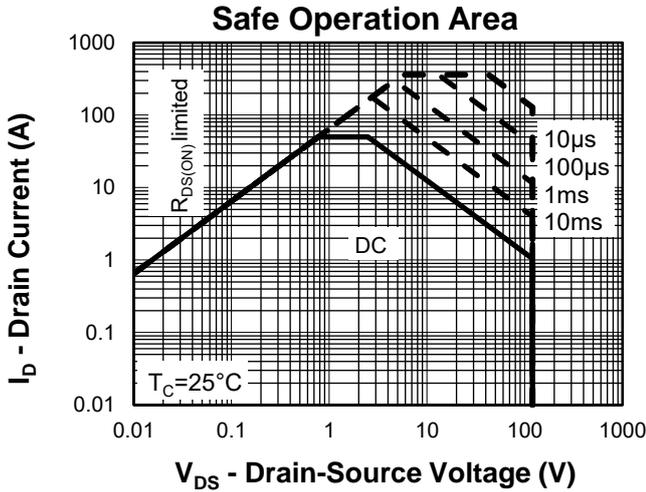
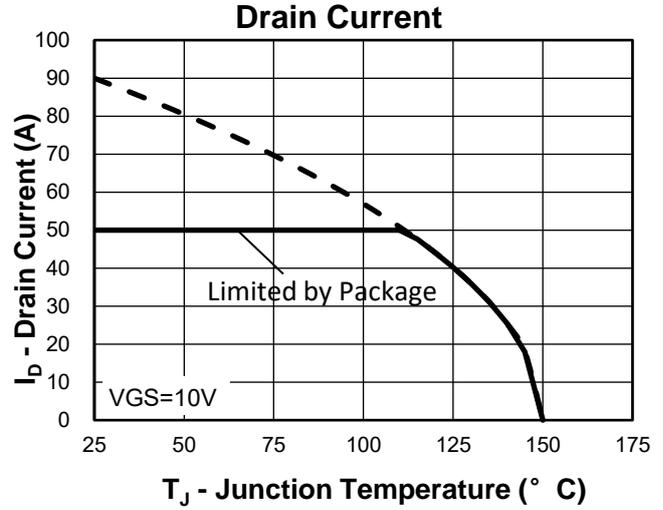
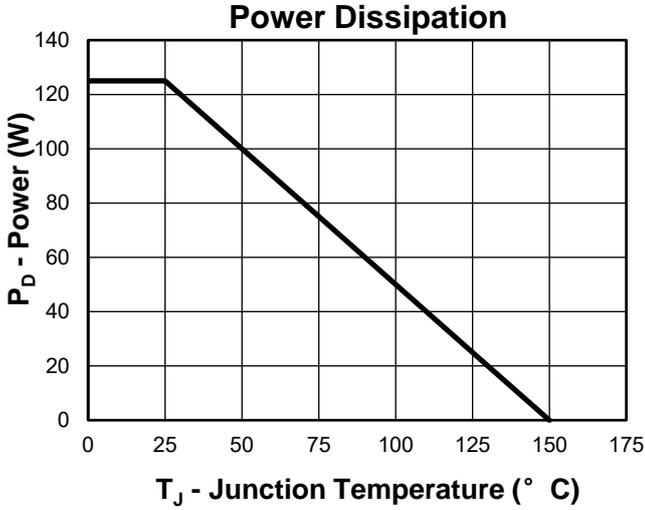
| Parameter                          | Symbol          | Conditions   | Min | Typ | Max | Unit |
|------------------------------------|-----------------|--|-----|-----|-----|------|
| Diode Forward Voltage <sup>2</sup> | V <sub>SD</sub> | V <sub>GS</sub> =0V, I <sub>S</sub> =20A, T <sub>J</sub> =25°C | --- | --- | 1.2 | V    |
| Reverse Recovery Time              | t <sub>rr</sub> | I <sub>F</sub> =20A<br>di/dt=100A/μs, T <sub>J</sub> =25°C     | --- | 55  | --- | nS   |
| Reverse Recovery Charge            | Q <sub>rr</sub> |  | --- | 68  | --- | nC   |

**Note:**

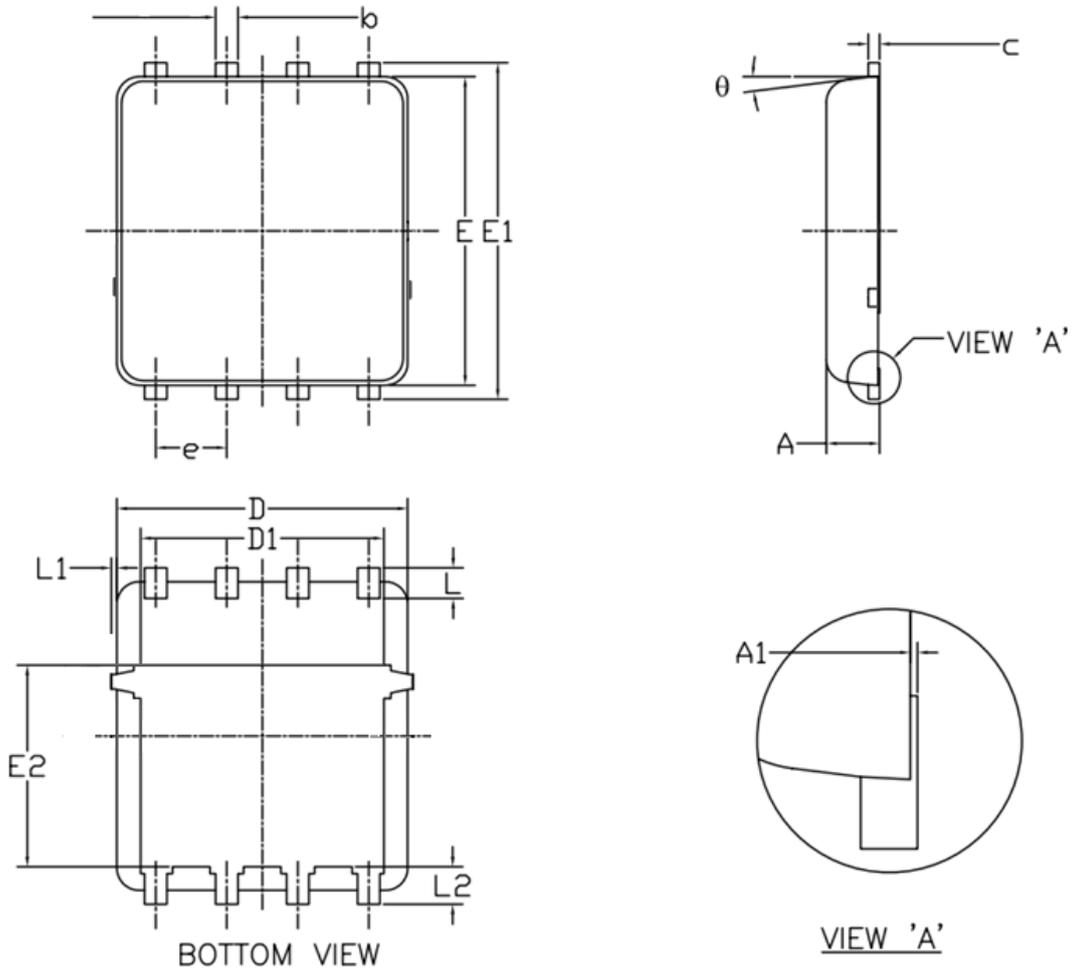
- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 20Z copper.
- 2.The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3.The EAS data shows Max. rating . The test condition is V<sub>DD</sub>=50V,R<sub>G</sub>=25Ω,L=0.5mH

**Typical Characteristics**





**DFN5X6-8L Package Outline Dimensions**



| Symbol    | Dimensions (unit:mm) |      |      | Symbol    | Dimensions (unit:mm) |      |      |
|-----------|----------------------|------|------|-----------|----------------------|------|------|
|           | Min                  | Typ  | Max  |           | Min                  | Typ  | Max  |
| <b>A</b>  | 0.90                 | 1.00 | 1.20 | <b>E1</b> | 5.90                 | 6.10 | 6.35 |
| <b>A1</b> | 0.00                 | --   | 0.05 | <b>E2</b> | 3.38                 | 3.58 | 3.92 |
| <b>b</b>  | 0.30                 | 0.40 | 0.51 | <b>e</b>  | 1.27 BSC             |      |      |
| <b>c</b>  | 0.20                 | 0.25 | 0.33 | <b>L</b>  | 0.51                 | 0.61 | 0.71 |
| <b>D</b>  | 4.80                 | 4.90 | 5.40 | <b>L1</b> | --                   | --   | 0.15 |
| <b>D1</b> | 3.61                 | 4.00 | 4.25 | <b>L2</b> | 0.41                 | 0.51 | 0.61 |
| <b>E</b>  | 5.65                 | 5.80 | 6.06 | <b>θ</b>  | 0°                   | --   | 12°  |